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General Description

The MAX382/MAX384 are low-voltage, CMOS, 1-of-8 and dual 4-channel muxes with latchable digital inputs. They feature low-voltage operation from a +2.7V to +16.5V single supply and from ±3V to ±8V dual supplies. Pin compatible with the DG428/DG429, these muxes offer low on-resistance (100 Ω max) matched to within 4Ω max between channels. Additional features include off leakage less than 2.5nA at +85°C and guaranteed low charge injection (10pC max). ESD protection is greater than 2000V per Method 3015.7.

Applications

Battery-Operated Systems Audio Signal Routing Low-Voltage Data-Acquisition Systems Sample-and-Hold Circuits Automatic Test Equipment

Features

- ♦ Pin-Compatible with Industry-Standard DG428/DG429, DG528/DG529, MAX368/MAX369
- ♦ Single-Supply Operation (+2.7V to +16.5V) Bipolar Supply Operation (±3V to ±8V)
- ♦ Low Power Consumption (<300µW)</p>
- **♦ Low On-Resistance, 100**Ω max
- **♦** Guaranteed On-Resistance Match Between Channels, 4Ω max
- ♦ Low Leakage, 2.5nA at +85°C
- **♦ TTL/CMOS-Logic Compatible**

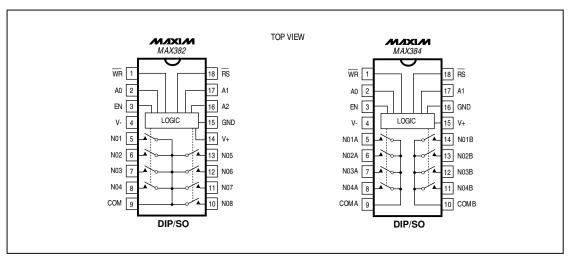
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX382CPN	0°C to +70°C	18 Plastic DIP
MAX382CWN	0°C to +70°C	18 Wide SO
MAX382C/D	0°C to +70°C	Dice*
MAX382EPN	-40°C to +85°C	18 Plastic DIP
MAX382EWN	-40°C to +85°C	18 Wide SO
MAX382EJN	-40°C to +85°C	18 CERDIP**
MAX382MJN	-55°C to +125°C	18 CERDIP**

Ordering Information continued on last page.

- Contact factory for dice specifications.
- ** Contact factory for package availability.

Pin Configurations



/VIXI/VI

Maxim Integrated Products 1

Call toll free 1-800-998-8800 for free samples or literature.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND
V+0.3V to +17V
V+0.3V to -17V
V+ to V0.3V to +17V
Voltage into Any Terminal (Note 1)($V-2V$) to ($V+2V$) or
30mA (whichever occurs first)
Current into Any Terminal30mA
Peak Current, Any Terminal
(pulsed at 1ms, 10% duty cycle max)100mA

Continuous Power Dissipation $(T_A = +70^{\circ}C)$	
Plastic DIP (derate 11.11mW/°C above +70°	°C)889mW
Wide SO (derate 9.52mW/°C above +70°C).	762mW
CERDIP (derate 10.53mW/°C above +70°C)	842mW
Operating Temperature Ranges	
MAX38_C_ N	0°C to +70°C
MAX38_E_ N	40°C to +85°C
MAX38_MJN	55°C to +125°C
Storage Temperature Range	
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on any terminal exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

 $(V_+ = +5V \pm 10\%, \ V_- = -5V \pm 10\%, \ GND = 0V, \ V_{A_H} = V_{ENH} = 2.4V, \ V_{A_L} = V_{ENL} = 0.8V, \ \overline{WR} = 0V, \ \overline{RS} = 2.4V, \ T_A = T_{MIN} \ to \ T_{MAX}, \ unless \ otherwise \ noted.)$

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS	
SWITCH									
Analog Signal Range	V _{COM} , V _{NO}	(Note 3)				V-		V+	V
Channel On-Resistance	Pau	INO = 1mA, VCOM =	+2 EV	$T_A = +25^{\circ}C$			60	100	Ω
Charmer On-nesistance	Ron	INO = IIIIA, VCOM =	±3.5V	T _A = T _{MIN} to	Тмах			125] 52
On-Resistance Matching	ΔRon	I _{NO} = 1mA, V _{COM} =	±3.5V,	T _A = +25°C				4	Ω
Between Channels (Note 4)	ΔηΟΝ	V+ = 5V, V- = -5V		$T_A = T_{MIN}$ to	T _{MAX}			6] 32
On-Resistance Flatness	RFLAT(ON)	INO = 1mA, VCOM =	±3V,	$T_A = +25$ °C				10	Ω
(Note 5)	THEAT(ON)	V+ = 5V, V- = -5V		T _A = T _{MIN} to	Тмах			13	32
NO 0"1 1 0 1		. 451/1/	-4.51/	$T_A = +25$ °C		-0.1		0.1	
NO-Off Leakage Current (Note 6)	I _{NO(OFF)}	V+ = J.J V. V- = -J.J V		TA = TMIN	C, E	-1.0		1.0	nA
(1.0.0.0)				to T _{MAX} M		-10		10	1
		$V_{COM} = \pm 4.5 V$,		T _A = +25°C		-0.2		0.2	
	ICOM(OFF)	V _{NO} = ∓4.5V, V+ = 5.5V, V- = -5.5V	MAX382	T _A = T _{MIN}	C, E	-2.5		2.5	
COM-Off Leakage Current				to T _{MAX}	М	-20		20	nA
(Note 6)		$V_{COM} = \pm 4.5 V$,	MAX384	T _A = +25°C		-0.1		0.1] "A
		V _{NO} = ∓4.5V,		T _A = T _{MIN}	C, E	-1.5		1.5	
		V+ = 5.5V, V- = -5.5V		to T _{MAX}	М	-10		10]
				T _A = +25°C		-0.4		0.4	
			MAX382	T _A = T _{MIN}	C, E	-5		5	
COM-On Leakage Current	ICOM(ON)	$V_{COM} = \pm 4.5V,$ $V_{NO} = 4.5V,$		to T _{MAX}	М	-40		40	nA
(Note 6)	ICOM(ON)	VNO = 4.3V,		T _A = +25°C		-0.2		0.2] "A
			MAX384	T _A = T _{MIN}	C, E	-2.5		2.5	
				to T _{MAX}	М	-20		20	

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued) (V+ = +5V \pm 10%, V- = -5V \pm 10%, GND = 0V, VA_H = VENH = 2.4V, VA_L = VENL = 0.8V, \overline{WR} = 0V, \overline{RS} = 2.4V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
DIGITAL LOGIC INPUT								•
Logic High Input Voltage	V _{A_H} , V _{ENH}			$T_A = T_{MIN}$ to T_{MAX}	2.4			V
Logic Low Input Voltage	V _{A_L} , V _{ENL}			$T_A = T_{MIN}$ to T_{MAX}			8.0	V
Input Current with Input Voltage High	IA_H, IENH	V _{A_H} = 2.4V, V _{A_L} =	0.8V		-0.1		0.1	μА
Input Current with Input Voltage Low	I _{A_L} , I _{ENL}	V _{A_H} = 2.4V, V _{A_L} =	V8.0		-0.1		0.1	μА
SUPPLY								1
Power-Supply Range	V+, V-				±2.4		±8	V
Positive Supply Current	l+	V _{EN} = V _A = 0V/V+, V+ = 5.5V, V- = -5.5	V	T _A = +25°C	-1		1	μА
Negative Supply Current	I-	VEN = VA = 0V/V+, V+ = 5.5V, V- = -5.5	V	TA = TMIN to TMAX	-1		1	μА
AX, EN Data Hold Time	tH	Figure 5		T _A = +25°C	100			ns
Reset Pulse Width	tRS	Figure 6, V+ = 5V		T _A = +25°C	100			ns
DYNAMIC					•			•
Transition Time	ttrans	Figure 1				100	275	ns
Break-Before-Make Interval	topen	Figure 2		T _A = +25°C	0	20		ns
Enable Turn-On Time	tonum	Figure 3		T _A = +25°C		100	150	ns
Enable fulli-On fillie	ton(EN)	rigule 3		TA = TMIN to TMAX			250	7 115
Enable Turn-Off Time	t	Figure 0		T _A = +25°C		80	150	no
Lilable fulli-Oil fillie	toff(EN)	Figure 3		$T_A = T_{MIN}$ to T_{MAX}			250	ns
Write Turn-On Time	tona	Figure 4		T _A = +25°C			150	ns
write rum-on nine	ton(WR)	rigule 4		$T_A = T_{MIN}$ to T_{MAX}			250] 115
Reset Turn-Off Time	to==(Figure 6		T _A = +25°C			150	ns
neset fulli-Oil fillie	toff(RS)	i igule o		TA = TMIN to TMAX			250	7 115
Charge Injection (Note 3)	V _{CTE}	C _L = 100pF, V _{NO} = 0	V	T _A = +25°C		2	5	pC
Off Isolation (Note 7)	V _{ISO}	$V_{EN} = 0V$, $R_L = 1k\Omega$,	f = 100kHz	T _A = +25°C		-75		dB
Crosstalk Between Channels	Vст	V _{EN} = 2.4V, f = 100kl V _{GEN} = 1V _{p-p} , R _L = 1	,	T _A = +25°C		-92		dB
Logic Input Capacitance	CIN	$f = 1MHz$ $T_A = +25$ °C		T _A = +25°C		8		pF
NO-Off Capacitance	C _{NO(OFF)}	f = 1MHz, V _{EN} = V _C	OM = 0V	T _A = +25°C		11		pF
	, ,	f = 1MHz,	MAX382			40		<u> </u>
COM-Off Capacitance	-Off Canacitance CCOMOEE	MAX384	T _A = +25°C		20		→ pF	
2011.0	_	f = 1MHz,	MAX382	T 0500		54		<u> </u>
COM-On Capacitance	C _{COM(ON)}	V _{EN} = V _{COM} = 0V	MAX384	$T_A = +25^{\circ}C$		34		pF
MINIMUM INPUT TIMING RI	EQUIREMEN	its	1	L	1			
Write Pulse Width	tw	Figure 5		T _A = +25°C	100			ns
AX, EN Data Setup Time	ts	Figure 5		T _A = +25°C	100			ns

ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V+=+5V\pm10\%,\ V-=0V,\ GND=0V,\ VA_H=VENH=2.4V,\ VA_L=VENL=0.8V,\ \overline{WR}=0V,\ \overline{RS}=2.4V,\ TA=T_{MIN}\ to\ T_{MAX},\ unless otherwise noted.)$

PARAMETER	SYMBOL	(CONDITION	IS		MIN	TYP (Note 2)	MAX	UNITS	
AX, EN Data Hold Time	tH	Figure 5		T _A = +25°C		100			ns	
Reset Pulse Width	tRS	Figure 6, V+ = 5V $T_A = +25$ °C		100			ns			
SWITCH	•								•	
Analog Signal Range	V _{COM} , V _{NO}	(Note 3)				V-		V+	V	
On-Resistance	Pou	I _{NO} = 1mA, V _{COM} =	3.5V,	T _A = +25°C			150	225	Ω	
On-Resistance	Ron	V+ = 4.5V		T _A = T _{MIN} to	TMAX			280] 12	
On-Resistance Matching	ΔRon	INO = 1mA, V _{COM} =	3.5V,	T _A = +25°C				10	Ω	
Between Channels (Note 4)	ΔHON	V+ = 4.5V		TA = TMIN to	T _{MAX}			12	1 22	
On-Resistance Flatness	R _{FLAT}	I _{NO} = 1mA; V _{COM} =	3V, 2V, 1V;	$T_A = +25^{\circ}C$			10	16	Ω	
On-nesistance riatness	T-LA1	V+ = 5V		T _A = T _{MIN} to	T _{MAX}		15	20] 12	
NO Off Lanks are Owners		V 4.5V.V	0)/	T _A = +25°C		-0.1		0.1		
NO-Off Leakage Current (Note 8)	I _{NO(OFF)}	$V_{NO} = 4.5V, V_{COM} = V_{+} = 5.5V$	= UV,	$T_A = T_{MIN}$	C, E	-1.0		1.0	nA	
(11010 0)				to T _{MAX}	М	-10		10		
		V _{COM} = 4.5V,		T _A = +25°C	•	-0.2		0.2		
		$V_{NO} = 0V$,	MAX382	T _A = T _{MIN}	C, E	-2.5		2.5		
COM-Off Leakage Current	loower	V+ = 5.5V		to T _{MAX}	М	-20		20	nA	
(Note 8)	ICOM(OFF)	V _{OOM} = 4.5 V, V _{NO} = 0 V, MAX384 T	T _A = +25°C	-0.2		0.2] "			
			MAX384	T _A = T _{MIN}	C, E	-1.5		1.5]	
			to T _{MAX}	М	-10		10			
				T _A = +25°C	•	-0.4		0.4		
		V _{COM} = 4.5V, V _{NO} = 4.5V,	MAX382	1 . \(\tau \) . IMIII.	C, E	-5		5		
COM-On Leakage Current	ICOM(ON)			to T _{MAX}	М	-40		40	nA	
(Note 8)	ICOM(ON)	$V_{NO} = 4.5V$, $V_{+} = 5.5V$		$T_A = +25$ °C		-0.2		0.2] "A	
			MAX384	T _A = T _{MIN}	C, E	-2.5		2.5]	
				to T _{MAX}	М	-20		20		
DIGITAL LOGIC INPUT										
Logic High Input Voltage	V _H , V _{ENH}			$T_A = T_{MIN}$ to	T _{MAX}	2.4			V	
Logic Low Input Voltage	V _L , V _{ENL}			$T_A = T_{MIN}$ to	T _{MAX}			0.8	V	
Input Current with Input Voltage High	IH, IENH	V _H = 2.4V, V _L = 0.8V		-0.1		0.1	μА			
Input Current with Input Voltage Low	IL, I _{ENL}	V _H = 2.4V, V _L = 0.8V		-0.1		0.1	μА			
SUPPLY		1							-	
Power-Supply Range						2.4		15	V	
Positive Supply Current	I+	VEN = VA = 0V, V+; V+ = 5.5V; V- = 0V			-1.0		1.0	μΑ		
Negative Supply Current	I-	V _{EN} = V _A = 0V, V+; V+ = 5.5V; V- = 0V			-1.0		1.0	μΑ		
J 0	1	V _{EN} = V+, 0V; V _A =	0V;	T _A = +25°C		-1.0		1.0		
IGND Supply Current	IGND	V+ = 5.5V; V- = 0V	•	T _A = T _{MIN} to	T _{MAX}	-1.0		1.0	μΑ	

MIXIM

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

 $(V+=+5V\pm10\%, V-=0V, \text{GND}=0V, \text{VA}_{\underline{\textbf{H}}}=\text{V}_{\underline{\textbf{ENH}}}=2.4V, \text{VA}_{\underline{\textbf{L}}}=\text{V}_{\underline{\textbf{ENL}}}=0.8V, \overline{WR}=0V, \overline{RS}=2.4V, T_{\underline{\textbf{A}}}=T_{\underline{\textbf{MIN}}}$ to $T_{\underline{\textbf{MAX}}}$, unless otherwise noted.)

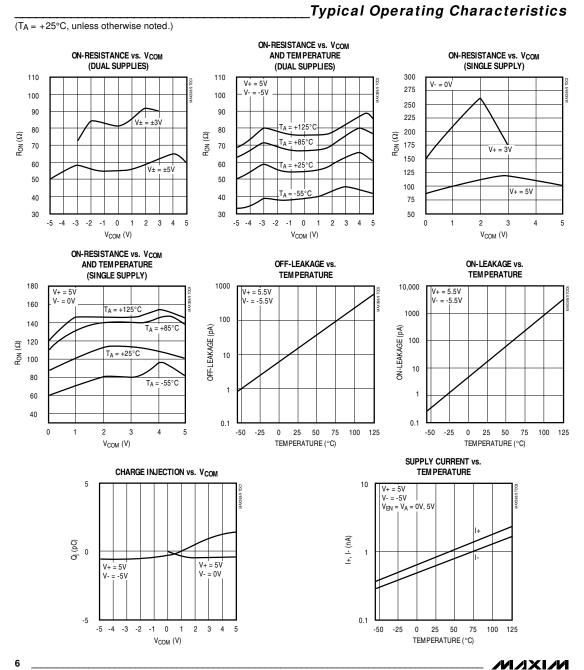
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DYNAMIC							
Transition Time	ttrans	Figure 1, V _{NO} = 3V			90	280	ns
Break-Before-Make Interval	topen	Figure 2 (Note 3)	T _A = +25°C	5	40		ns
Enable Turn-On Time	ta	Figure 3	T _A = +25°C		130	200	no
(Note 3)	ton(EN)	rigule 3	$T_A = T_{MIN}$ to T_{MAX}			275	ns
Enable Turn-Off Time	t	Figure 3	T _A = +25°C		80	200	no
(Note 3)	toff(EN)	rigule 3	$T_A = T_{MIN}$ to T_{MAX}			275	ns
Write Turn-On Time	tova	Figure 4	T _A = +25°C			200	
(Note 3)	ton(WR)	rigule 4	TA = TMIN to TMAX			275	ns
Reset Turn-Off Time	to=====	Figure 4	T _A = +25°C			200	no
(Note 3)	toff(RS)	riguie 4	$T_A = T_{MIN}$ to T_{MAX}			275	ns
Charge Injection (Note 3)	V _{CTE}	Figure 7, C _L = 100pF, V _{NO} = 0V	T _A = +25°C		1.5	5	pC

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +3V \pm 10%, V- = 0V, GND = 0V, VA_H = VENH = 2.4V, VA_L = VENL = 0.8V, \overline{WR} = 0V, \overline{RS} = 2.4V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	Vanalog	(Note 3)		V-		V+	V
On-Resistance	Ron	I _{NO} = 1mA, V _{COM} = 1.5V,	T _A = +25°C		230	375	Ω
Oli-nesistatice	HON	V+ = 3V	$T_A = T_{MIN}$ to T_{MAX}			425	1 12
DYNAMIC						•	
Transition Time (Note 3)	ttrans	Figure 1, V _{IN} = 2.4V, V _{N01} = 1.5V, V _{N08} = 0V	T _A = +25°C		230	575	ns
Enable Turn-On Time (Note 3)	ton(EN)	Figure 3, V _{INH} = 2.4V, V _{INL} = 0V, V _{N01} = 1.5V	T _A = +25°C		200	500	ns
Enable Turn-Off Time (Note 3)	toff(EN)	Figure 3, V _{INH} = 2.4V, V _{INL} = 0V, V _{N01} = 1.5V	T _A = +25°C		75	400	ns
Write Turn-On Time (Note 3)	ton(WR)	Figure 4	T _A = +25°C		200	500	ns
Reset Turn-Off Time (Note 3)	toff(RS)	Figure 4	T _A = +25°C		75	400	ns
Charge Injection (Note 3)	VCTE	Figure 7, C _L = 100pF, V _{NO} = 0V	T _A = +25°C		1	5	рС

- Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- Note 4: $\Delta R_{ON} = R_{ON}(max) R_{ON}(min)$.
- Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges, i.e., $V_{NO} = 3V$ to 0V and 0V to -3V.
- Note 6: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at +25°C.
- Note 7: Worst-case isolation is on channel 4 because of its proximity to the COM pin. Off isolation = 20log V_{COM}/V_{NO} , V_{COM} = output, V_{NO} = input to off switch.
- Note 8: Leakage testing at single supply is guaranteed by correlation testing with dual supplies.



Pin Description

Р	PIN		FUNCTION
MAX382	MAX384	- NAME*	FUNCTION
1	1	WR	WRITE Logic Input
2, 16, 17	_	A0, A2, A1	Address Logic Inputs (see Truth Tables at end of data sheet)
_	2, 17	A0, A1	Address Logic Inputs (see Truth Tables at end of data sheet)
3	3	EN	Enable Logic Input (see Truth Tables at end of data sheet)
4	4	V-	Negative Supply Voltage Input. Connect to GND for single-supply operation.
5–8	_	NO1-NO4	Analog Signal Inputs—bidirectional
_	5–8	NO1A-NO4A	Analog Signal Inputs—bidirectional
9	_	COM	Analog Signal Output—bidirectional
_	9, 10	COMA, COMB	Analog Signal Outputs—bidirectional
10–13	_	NO8–NO5	Analog Signal Inputs—bidirectional
_	11–14	NO4B-NO1B	Analog Signal Inputs—bidirectional
14	15	V+	Positive Supply Voltage Input
15	16	GND	Ground
18	18	RS	RESET Logic Input

^{*}Analog inputs and outputs are names of convenience only. Inputs and outputs are identical and interchangeable.

Applications Information

The internal structures of the MAX382/MAX384 include translators for the A2/A1/EN/WR/RS digital inputs, latches, and a decode section for channel selection (see *Truth Tables*). The analog-signal switches consist of parallel combinations of N and P MOSFETs.

 $\overline{\text{WRITE}}$ ($\overline{\text{WR}}$) and $\overline{\text{RESET}}$ ($\overline{\text{RS}}$) strobes are provided for interfacing with μP -bus lines, alleviating the need for the μP to provide constant address inputs to the mux to hold a particular channel (Figures 2–7).

When the $\overline{\text{WR}}$ strobe is in the low state (less than 0.8V) and the $\overline{\text{RS}}$ strobe is in the high state (greater than 2.4V), the muxes are in the transparent mode—they act similar to nonlatching devices, such as the MAX398/MAX399.

When the $\overline{\text{WR}}$ goes high, the previous BCD address input is latched and held in that state indefinitely.

 \overline{RS} turns off all channels when it is low. All switches stay off until \overline{RS} and \overline{EN} are high and \overline{WR} is low.

The MAX382/MAX384 work with both single and dual supplies and function over the +2.4V to +16V single-supply range. For example, with a single +5V power supply, analog signals in the 0V to +5V range can be switched normally. If negative signals around 0V are expected, a negative supply is needed.

The EN latch allows all switches to be turned off under program control. This is useful when two or more are cascaded to build 16-line and larger analog-signal multiplexers.

_Test Circuits/Timing Diagrams

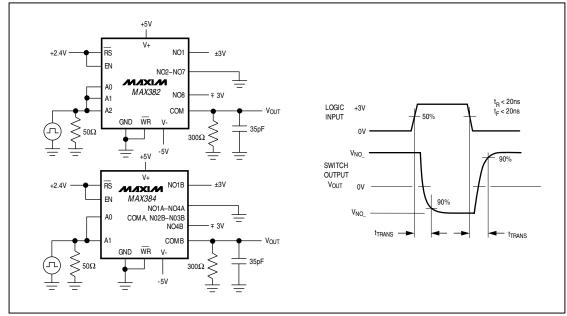


Figure 1. Transition Time

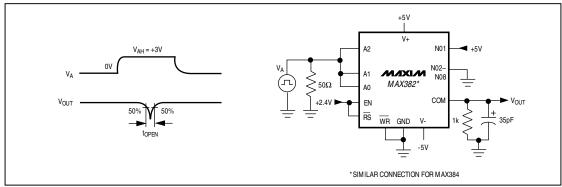


Figure 2. Break-Before-Make Interval (t_{OPEN})

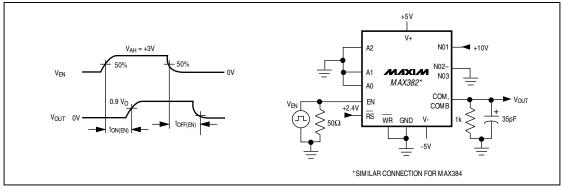


Figure 3. Enable Delay (ton(EN), toff(EN))

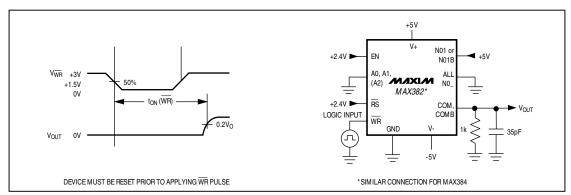


Figure 4. Write Turn-On Time (ton(\overline{WR}))

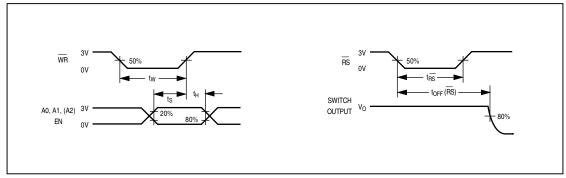


Figure 5. Write, Setup, and Hold Timing (tw, ts, th)

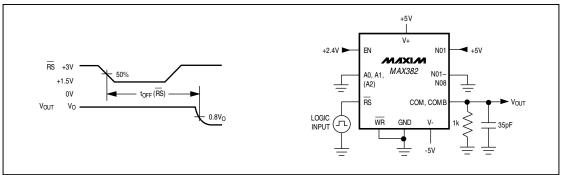


Figure 6. Reset Turn-Off Time (tOFF(RS))

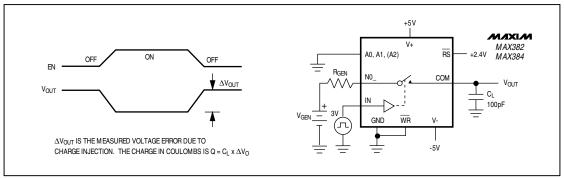


Figure 7. Charge Injection (VCTE)

Operation with Supply Voltages Other than ±5V

Using supply voltages less than $\pm 5\text{V}$ reduces the analog signal range. The MAX382/MAX384 muxes operate with $\pm 3\text{V}$ to $\pm 8\text{V}$ bipolar supplies or with a +2.7V to +16.5V single supply. Connect V- to GND when operating with a single supply. Both devices can also operate with unbalanced supplies, such as +10V and -5V. The *Typical Operating Characteristics* graphs show typical on-resistance with $\pm 3\text{V}$, $\pm 5\text{V}$, +3V and +5V supplies. (Switching times increase by a factor of two or more for operation at +5V or below.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with supply pins for overvoltage protection (Figure 8). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 17V. These protection diodes are not recommended when using a single supply.

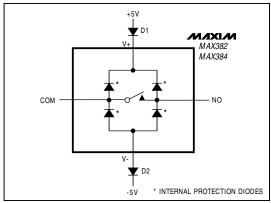
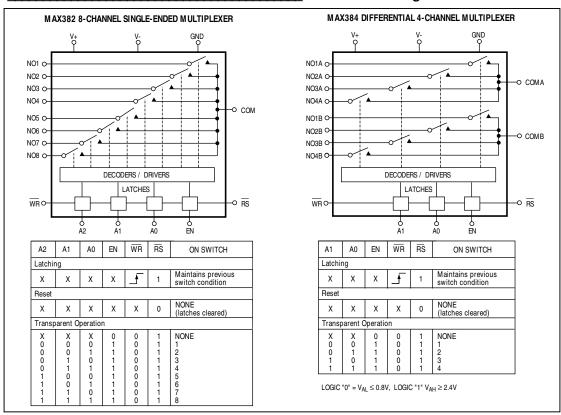


Figure 8. Overvoltage Protection Using External Blocking Diodes

Functional Diagrams/Truth Tables



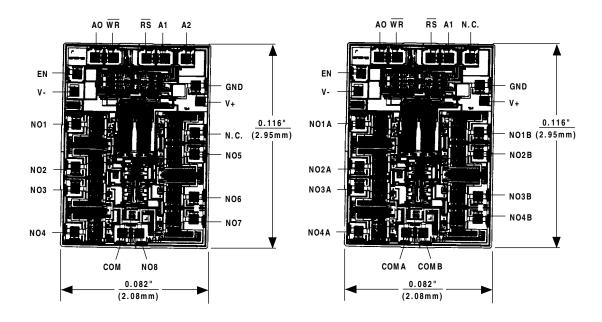
_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX384CPN	0°C to +70°C	18 Plastic DIP
MAX384CWN	0°C to +70°C	18 Wide SO
MAX384C/D	0°C to +70°C	Dice*
MAX384EPN	-40°C to +85°C	18 Plastic DIP
MAX384EWN	-40°C to +85°C	18 Wide SO
MAX384EJN	-40°C to +85°C	18 CERDIP**
MAX384MJN	-55°C to +125°C	18 CEBDIP**

- * Contact factory for dice specifications.
- ** Contact factory for package availability.

_____Chip Topographies

MAX382 MAX384



TRANSISTOR COUNT: 165 SUBSTRATE CONNECTED TO V+

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